

SN74AHCT245-Q1 Automotive Octal Bus Transceivers With 3-State Outputs

1 Features

- AEC-Q100 qualified for automotive applications: Temperature grade 1: –40°C to +125°C, T_A
- Inputs are TTL-voltage compatible
- Latch-up performance exceeds 250mA per JESD 17

2 Applications

- Enable or disable a digital signal
- Hold a signal during a controller reset
- Debounce a switch

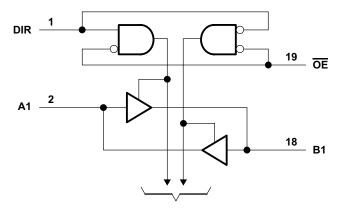
3 Description

The SN74AHCT245-Q1 octal bus transceivers are designed for asynchronous two-way communication between data buses. These parts operate from 4.5V to 5.5V.

Package Information

PART NUMBER	PART NUMBER PACKAGE (1)		BODY SIZE (NOM)(3)
SN74AHCT245-Q1	PW (TSSOP, 20)	6.5mm × 6.4mm	6.5mm × 4.4mm
311/4AI1C1243-Q1	DGS (VSSOP, 20)	5.1mm × 4.9mm	5.1mm × 3mm

- For all available packages, see Section 13. (1)
- The package size (length × width) is a nominal value and (2) includes pins, where applicable.
- The body size (length × width) is a nominal value and does not include pins.



To Seven Other Channels

Simplified Schematic



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4 Pin Configuration and Functions

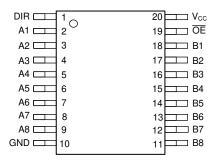


Figure 4-1. SN74AHCT245-Q1: PW or DGS Package, 20-Pin TSSOP or VSSOP (Top View)

Table 4-1. Pin Functions

F	PIN TYPE ⁽¹⁾		DESCRIPTION
NAME	NO.	- ITPE("/	DESCRIPTION
DIR	1	ı	Direction Pin
A1	2	I/O	A1 Input/Output
A2	3	I/O	A2 Input/Output
A3	4	I/O	A3 Input/Output
A4	5	I/O	A4 Input/Output
A5	6	I/O	A5 Input/Output
A6	7	I/O	A6 Input/Output
A7	8	I/O	A7 Input/Output
A8	9	I/O	A8 Input/Output
GND	10	G	Ground Pin
B8	11	I/O	B8 Input/Output
B7	12	I/O	B7 Input/Output
B6	13	I/O	B6 Input/Output
B5	14	I/O	B5 Input/Output
B4	15	I/O	B4 Input/Output
B3	16	I/O	B3 Input/Output
B2	17	I/O	B2 Input/Output
B1	18	I/O	B1 Input/Output
ŌĒ	19	I	Output Enable
VCC	20	Р	Power Pin

⁽¹⁾ I = Input, O = Output, P= Positive Supply, G = Ground



5 Specifications

5.1 Absolute Maximum Ratings

over operating free-air temperature range (unless otherwise noted)(1)

					MIN	MAX	UNIT
V _{CC}	Supply voltage range				-0.5	7	V
VI	Input voltage range ⁽²⁾			Control inputs	-0.5	7	V
Vo	Output voltage range ⁽²⁾				-0.5	V _{CC} + 0.5	V
I _{IK}	Input clamp current	V _I < 0		Control inputs		-20	mA
I _{OK}	Output clamp current	$V_O < 0$ or $V_O > 1$	V _{CC}			±20	mA
Io	Continuous output current	$V_O = 0$ to V_{CC}				±25	mA
	Continuous current through V _{CC} or GND				±75	mA	
T _{stg}	Storage temperature				-65	150	°C

⁽¹⁾ Operation outside the Absolute Maximum Rating may cause permanent device damage. Absolute Maximum Rating do not imply functional operation of the device at these or any other conditions beyond those listed under Recommended Operating Condition. If used outside the Recommended Operating Condition but within the Absolute Maximum Rating, the device may not be fully functional, and this may affect device reliability, functionality, performance, and shorten the device lifetime.

5.2 ESD Ratings

				MIN	MAX	UNIT
	V _(ESD) Electrostatic discharge	Human body model (HBM), per AEC Q100-002 HBM ESD Classification Level 2 ⁽¹⁾		±2000	V	
ľ	(ESD)	Electrostatic discharge	Charged device model (CDM), per AEC Q100-011 CDM ESD Classification Level C4B		±1000	V

⁽¹⁾ AEC Q100-002 indicate that HBM stressing shall be in accordance with the ANSI/ESDA/JEDEC JS-001 specification.

5.3 Recommended Operating Conditions

over operating free-air temperature range (unless otherwise noted)(1)

		SN74AHCT2	45-Q1	UNIT
		MIN	MAX	UNII
V _{CC}	Supply voltage	4.5	5.5	V
V _{IH}	High-level input voltage	2		V
V _{IL}	Low-level Input voltage		0.8	V
VI	Input voltage	0	5.5	V
Vo	Output voltage	0	Vcc	V
I _{OH}	High-level output current		-8	mA
I _{OL}	Low-level output current		8	mA
Δt/Δν	Input Transition rise and fall rate		20	ns/V
T _A	Operating free-air temperature	-40	125	°C

⁽¹⁾ All unused inputs of the device must be held at V_{CC} or GND for proper device operation. Refer to the TI application report, *Implications of Slow or Floating CMOS Inputs*, literature number SCBA004.

Product Folder Links: SN74AHCT245-Q1

⁽²⁾ The input and output voltage ratings may be exceeded if the input and output current ratings are observed.



5.4 Thermal Information

			SN74AH0		
	THERMAL METRIC ⁽¹⁾		PW	DGS	UNIT
			20 PINS	20 PINS	
$R_{\theta JA}$	Junction-to-ambient thermal resistance		102.8	118.4	
R _{θJC(top)}	Junction-to-case (top) thermal resistance		36.8	57.7	
$R_{\theta JB}$	Junction-to-board thermal resistance		53.8	73.1	°C/W
Ψлт	Junction-to-top characterization parameter		2.5	5.7	C/VV
ΨЈВ	Junction-to-board characterization parameter		53.3	72.7	
R _{0JC(bot)}	Junction-to-case (bottom) thermal resistance		n/a	n/a	

⁽¹⁾ For more information about traditional and new thermal metrics, see the Semiconductor and IC Package Thermal Metrics application

5.5 Electrical Characteristics

over recommended operating free-air temperature range (unless otherwise noted)

DAI	RAMETER	TEST CONDITIONS	V	T	_λ = 25°C		-40°C to 12	5°C	UNIT
FAI	KAWETEK	TEST CONDITIONS	V _{cc}	MIN	TYP	MAX	MIN	MAX	UNIT
V _{OH}		I _{OH} = -50 μA	4.5 V	4.4	4.5		4.4		V
VOH		I _{OH} = -8 mA	4.5 V	3.94			3.7		V
V		I _{OL} = 50 μA	4.5 V			0.1		0.1	V
V _{OL}		I _{OH} = 8 mA	4.5 V			0.36		0.44	V
I	OE or DIR	V _I = 5.5 V or GND	0 to 5.5 V			±0.1		±1	μΑ
I _{OZ}	A or B inputs ⁽¹⁾	V _O = V _{CC} or GND	5.5 V			±.25		±2.5	μA
Icc		$V_I = V_{CC}$ or GND, $I_O = 0$	5.5 V			4		40	μΑ
ΔI _{CC} (2)		One input at 3.4 V, Other inputs at V _{CC} or GND	5.5 V			1.35		1.5	mA
C _i	OE or DIR	V _I = V _{CC} or GND	5 V		2.5	10			pF
C _{io}	A or B inputs	V _I = V _{CC} or GND	5 V		4				pF

For I/O ports, the parameter I_{OZ} includes the input leakage current. This is the increase in supply current for each input at one of the specified TTL voltage levels, rather than 0 V or V_{CC} . (1) (2)



5.6 Switching Characteristics

over recommended operating free-air temperature range, V_{CC} = 5 V \pm 0.5 V (unless otherwise noted)

PARAMETER	FROM	то	LOAD	T _A = 25°	C	-40°C to 1	125°C	UNIT
PARAMETER	(INPUT)	(OUTPUT)	CAPACITANCE	TYP	MAX	MIN	MAX	UNIT
t _{PLH}	A or B	B or A	C _L = 15 pF	4.5	7.7	1	10	ns
t _{PHL}	AOIB	BOIA	OL = 13 pi	4.5	7.7	1	10	115
t _{PZH}	ŌĒ	A or B	C _L = 15 pF	8.9	13.8	1	16	ns
t _{PZL}	OE .	AOIB	C _L = 15 pr	8.9	13.8	1	16	115
t _{PHZ}	ŌĒ	A or B	C _L = 15 pF	9.2	14.4	1	16.5	ns
t _{PLZ}		AOIB	OL = 13 pi	9.2	14.4	1	16.5	115
t _{PLH}	A or B	B or A	C _L = 50 pF	5.3	8.7	1	11	ns
t _{PHL}	AOIB	BOIA	О[– 30 рі	5.3	8.7	1	11	115
t _{PZH}	 OE	A or B	C _L = 50 pF	9.7	14.8	1	17	ns
t _{PZL}	OE .	AOIB	C _L = 50 pr	9.7	14.8	1	17	115
t _{PHZ}	ŌĒ	A or B	C _L = 50 pF	10	15.4	1	17.5	ns
t _{PLZ}) JE	AUIB	GL = 50 pF	10	15.4	1	17.5	115
t _{sk(o)}			C _L = 50 pF		1			ns

5.7 Noise Characteristics

 $V_{CC} = 5 \text{ V}, C_L = 50 \text{ pF}, T_A = 25^{\circ}C^{(1)}$

	PARAMETER		SN74AHCT245-Q1		
	PARAINETER	MIN	TYP	MAX	UNIT
V _{OH(V)}	Quiet output, minimum dynamic V _{OH}		4		V
V _{IH(D)}	High-level dynamic input voltage	2			V
V _{IL(D)}	Low-level dynamic input voltage			0.8	V

⁽¹⁾ Characteristics are for surface-mount packages only.

5.8 Operating Characteristics

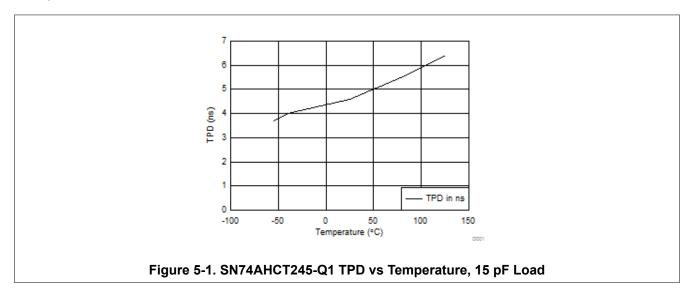
 V_{CC} = 5 V, T_A = 25°C

	PARAMETER		NDITIONS	TYP	UNIT
C _{pd}	Power dissipation capacitance	No load,	f = 1 MHz	13	pF

Product Folder Links: SN74AHCT245-Q1

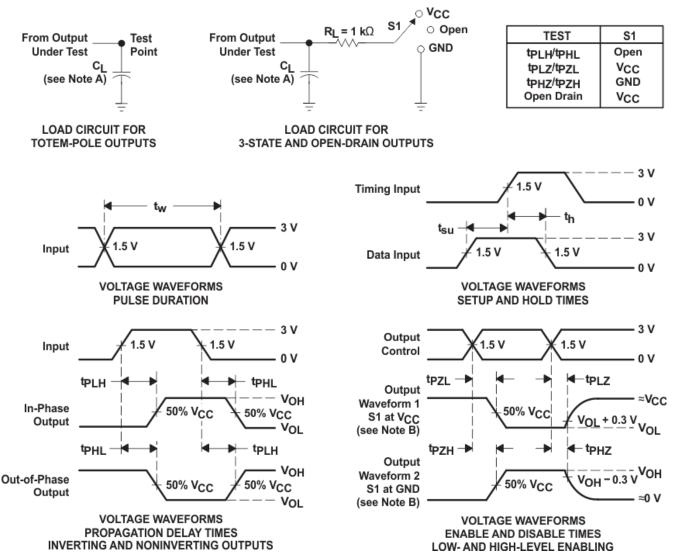


5.9 Typical Characteristics





6 Parameter Measurement Information



- A. C_L includes probe and jig capacitance.
- B. Waveform 1 is for an output with internal conditions such that the output is low except when disabled by the output control. Waveform 2 is for an output with internal conditions such that the output is high except when disabled by the output control.
- C. All input pulses are supplied by generators having the following characteristics: PRR \leq 1 MHz, $Z_O = 50 \Omega$, $t_r \leq 3 \text{ ns}$
- D. The outputs are measured one at a time with one input transition per measurement.
- E. All parameters and waveforms are not applicable to all devices.

Figure 6-1. Load Circuit and Voltage Waveforms

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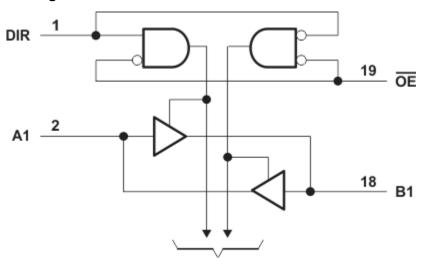
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7 Detailed Description

7.1 Overview

The SNx7ACHT245 octal bus transceivers are designed for asynchronous two-way communication between data buses. The control-function implementation minimizes external timing requirements. The SN74AHCT245-Q1 devices allow data transmission from the A bus to the B bus or from the B bus to the A bus, depending on the logic level at the direction–control (DIR) input. The output-enable (\overline{OE}) input can be used to disable the device so that the buses effectively are isolated. For the high-impedance state during power up or power down, \overline{OE} should be tied to V_{CC} through a pullup resistor; the minimum value of the resistor is determined by the current-sinking capability of the driver.

7.2 Functional Block Diagram



To Seven Other Channels

Figure 7-1. Logic Diagram (Positive Logic)

7.3 Feature Description

- V_{CC} is optimized at 5 V
- Allows up voltage translation from 3.3 V to 5 V
 - Inputs accept V_{IH} levels of 2 V
- · Slow edge rates minimize output ringing

7.4 Device Functional Modes

Table 7-1. Function Table (Each Transceiver)

INP	UTS	OPERATION		
ŌĒ	DIR	OPERATION		
L	L	B data to A bus		
L	Н	A data to B bus		
Н	Х	Isolation		

8 Application and Implementation

Note

Information in the following applications sections is not part of the TI component specification, and TI does not warrant its accuracy or completeness. TI's customers are responsible for determining suitability of components for their purposes, as well as validating and testing their design implementation to confirm system functionality.

8.1 Application Information

The SN74AHCT245 is a low drive CMOS device that can be used for a multitude of bus interface type applications where output ringing is a concern. The low drive and slow edge rates will minimize overshoot and undershoot on the outputs. The input switching levels have been lowered to accommodate TTL inputs of 0.8 V $V_{\rm IL}$ and 2 V $V_{\rm IH}$. This feature makes it ideal for translating up from 3.3 V to 5 V. The following figure shows this type of translation.

8.2 Typical Application

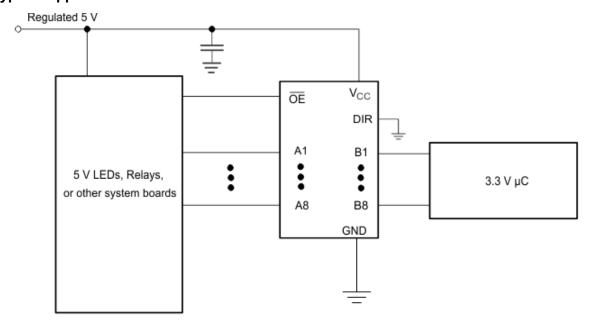


Figure 8-1. Typical Application Diagram

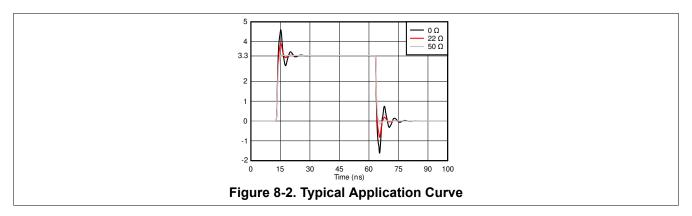
8.2.1 Design Requirements

This device uses CMOS technology and has a balanced output drive. Take care to avoid bus contention, because it can drive currents that would exceed maximum limits. The high drive will also create fast edges into light loads so routing and load conditions should be considered to prevent ringing.

8.2.2 Detailed Design Procedure

- Recommended input conditions:
 - Specified high and low levels. See (V_{IH} and V_{IL}) in the Recommended Operating Conditions table.
 - Specified high and low levels. See (V_{IH} and V_{IL}) in the Recommended Operating Conditions table.
 - Inputs are overvoltage tolerant allowing them to go as high as 5.5 V at any valid V_{CC}.
- Recommend output conditions:
 - Load currents should not exceed 25 mA per output and 50 mA total for the part.
 - Outputs should not be pulled above V_{CC}.

8.2.3 Application Curves



9 Power Supply Recommendations

The power supply can be any voltage between the MIN and MAX supply voltage rating located in the *Recommended Operating Conditions* table.

Each VCC pin should have a good bypass capacitor to prevent power disturbance. For devices with a single supply, 0.1 μ f is recommended; if there are multiple VCC pins, then 0.01 μ f or 0.022 μ f is recommended for each power pin. It is acceptable to parallel multiple bypass capacitors to reject different frequencies of noise. A 0.1 μ f and a 1 μ f are commonly used in parallel. The bypass capacitor should be installed as close to the power pin as possible for best results.

10 Layout

10.1 Layout Guidelines

When using multiple-bit logic devices, inputs should never float.

In many cases, functions or parts of functions of digital logic devices are unused, for example, when only two inputs of a triple-input AND gate are used or only 3 of the 4 buffer gates are used. Such input pins should not be left unconnected because the undefined voltages at the outside connections result in undefined operational states. Figure 10-1 specifies the rules that must be observed under all circumstances. All unused inputs of digital logic devices must be connected to a high or low bias to prevent them from floating. The logic level that should be applied to any particular unused input depends on the function of the device. Generally they will be tied to GND or V_{CC} , whichever makes more sense or is more convenient. It is generally acceptable to float outputs, unless the part is a transceiver. If the transceiver has an output enable pin, it will disable the output section of the part when asserted. This will not disable the input section of the I/Os, so they cannot float when disabled.

10.2 Layout Example

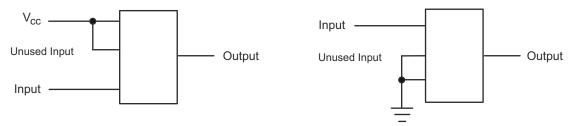


Figure 10-1. Layout Diagram



11 Device and Documentation Support

11.1 Receiving Notification of Documentation Updates

To receive notification of documentation updates, navigate to the device product folder on ti.com. Click on *Notifications* to register and receive a weekly digest of any product information that has changed. For change details, review the revision history included in any revised document.

11.2 Support Resources

TI E2E[™] support forums are an engineer's go-to source for fast, verified answers and design help — straight from the experts. Search existing answers or ask your own question to get the quick design help you need.

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11.3 Trademarks

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11.4 Electrostatic Discharge Caution



This integrated circuit can be damaged by ESD. Texas Instruments recommends that all integrated circuits be handled with appropriate precautions. Failure to observe proper handling and installation procedures can cause damage.

ESD damage can range from subtle performance degradation to complete device failure. Precision integrated circuits may be more susceptible to damage because very small parametric changes could cause the device not to meet its published specifications.

11.5 Glossary

TI Glossary

This glossary lists and explains terms, acronyms, and definitions.

12 Revision History

Changes from Revision * (April 2023) to Revision A (June 2025)

Page

Added DGS package......1

13 Mechanical, Packaging, and Orderable Information

The following pages include mechanical, packaging, and orderable information. This information is the most current data available for the designated devices. This data is subject to change without notice and revision of this document. For browser-based versions of this data sheet, refer to the left-hand navigation.

Product Folder Links: SN74AHCT245-Q1

www.ti.com 7-Nov-2025

PACKAGING INFORMATION

Orderable part number	Status	Material type	Package Pins	Package qty Carrier	RoHS (3)	Lead finish/ Ball material	MSL rating/ Peak reflow	Op temp (°C)	Part marking (6)
SN74AHCT245QDGSRQ1	Active	Production	VSSOP (DGS) 20	5000 LARGE T&R	Yes	NIPDAU	Level-1-260C-UNLIM	-40 to 125	CT245Q
SN74AHCT245QPWRQ1	Active	Production	TSSOP (PW) 20	2000 LARGE T&R	Yes	NIPDAU	Level-1-260C-UNLIM	-40 to 125	AHCT245Q
SN74AHCT245QPWRQ1.A	Active	Production	TSSOP (PW) 20	2000 LARGE T&R	Yes	NIPDAU	Level-1-260C-UNLIM	-40 to 125	AHCT245Q

⁽¹⁾ Status: For more details on status, see our product life cycle.

Multiple part markings will be inside parentheses. Only one part marking contained in parentheses and separated by a "~" will appear on a part. If a line is indented then it is a continuation of the previous line and the two combined represent the entire part marking for that device.

Important Information and Disclaimer: The information provided on this page represents TI's knowledge and belief as of the date that it is provided. TI bases its knowledge and belief on information provided by third parties, and makes no representation or warranty as to the accuracy of such information. Efforts are underway to better integrate information from third parties. TI has taken and continues to take reasonable steps to provide representative and accurate information but may not have conducted destructive testing or chemical analysis on incoming materials and chemicals. TI and TI suppliers consider certain information to be proprietary, and thus CAS numbers and other limited information may not be available for release.

In no event shall TI's liability arising out of such information exceed the total purchase price of the TI part(s) at issue in this document sold by TI to Customer on an annual basis.

OTHER QUALIFIED VERSIONS OF SN74AHCT245-Q1:

Catalog: SN74AHCT245

⁽²⁾ Material type: When designated, preproduction parts are prototypes/experimental devices, and are not yet approved or released for full production. Testing and final process, including without limitation quality assurance, reliability performance testing, and/or process qualification, may not yet be complete, and this item is subject to further changes or possible discontinuation. If available for ordering, purchases will be subject to an additional waiver at checkout, and are intended for early internal evaluation purposes only. These items are sold without warranties of any kind.

⁽³⁾ RoHS values: Yes, No, RoHS Exempt. See the TI RoHS Statement for additional information and value definition.

⁽⁴⁾ Lead finish/Ball material: Parts may have multiple material finish options. Finish options are separated by a vertical ruled line. Lead finish/Ball material values may wrap to two lines if the finish value exceeds the maximum column width.

⁽⁵⁾ MSL rating/Peak reflow: The moisture sensitivity level ratings and peak solder (reflow) temperatures. In the event that a part has multiple moisture sensitivity ratings, only the lowest level per JEDEC standards is shown. Refer to the shipping label for the actual reflow temperature that will be used to mount the part to the printed circuit board.

⁽⁶⁾ Part marking: There may be an additional marking, which relates to the logo, the lot trace code information, or the environmental category of the part.

PACKAGE OPTION ADDENDUM

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● Enhanced Product : SN74AHCT245-EP

Military: SN54AHCT245

NOTE: Qualified Version Definitions:

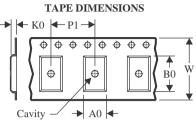
- Catalog TI's standard catalog product
- Enhanced Product Supports Defense, Aerospace and Medical Applications
- Military QML certified for Military and Defense Applications

PACKAGE MATERIALS INFORMATION

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TAPE AND REEL INFORMATION





A0	Dimension designed to accommodate the component width
В0	Dimension designed to accommodate the component length
K0	Dimension designed to accommodate the component thickness
W	Overall width of the carrier tape
P1	Pitch between successive cavity centers

QUADRANT ASSIGNMENTS FOR PIN 1 ORIENTATION IN TAPE

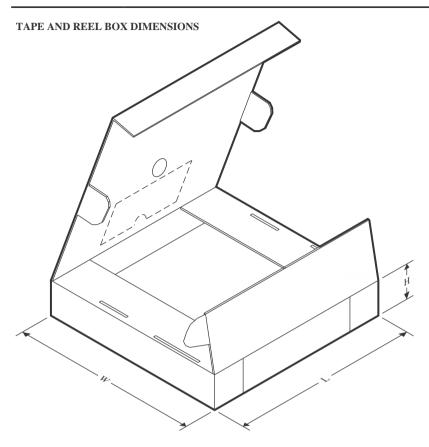


*All dimensions are nominal

Device	Package Type	Package Drawing		SPQ	Reel Diameter (mm)	Reel Width W1 (mm)	A0 (mm)	B0 (mm)	K0 (mm)	P1 (mm)	W (mm)	Pin1 Quadrant
SN74AHCT245QDGSRQ1	VSSOP	DGS	20	5000	330.0	16.4	5.4	5.4	1.45	8.0	16.0	Q1
SN74AHCT245QPWRQ1	TSSOP	PW	20	2000	330.0	16.4	6.95	7.0	1.4	8.0	16.0	Q1

PACKAGE MATERIALS INFORMATION

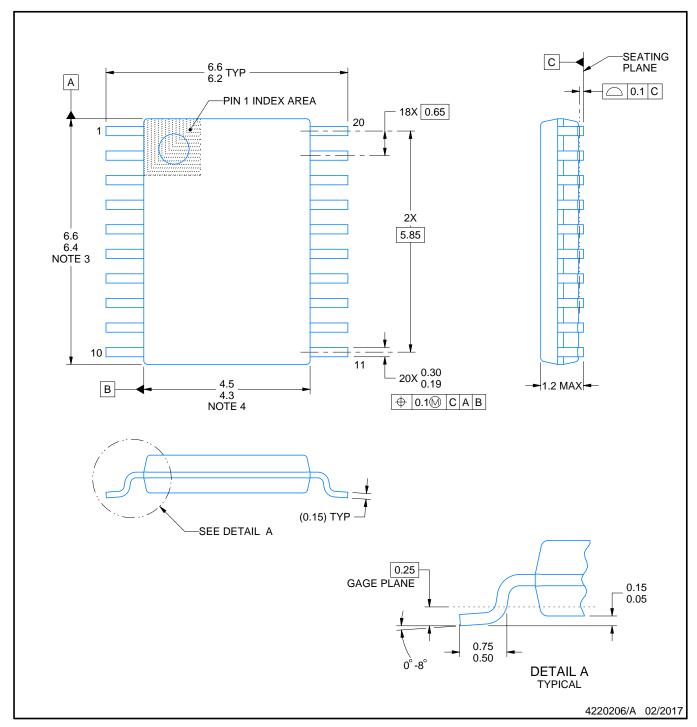
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*All dimensions are nominal

Device	Package Type	Package Drawing	Pins	SPQ	Length (mm)	Width (mm)	Height (mm)
SN74AHCT245QDGSRQ1	VSSOP	DGS	20	5000	353.0	353.0	32.0
SN74AHCT245QPWRQ1	TSSOP	PW	20	2000	353.0	353.0	32.0





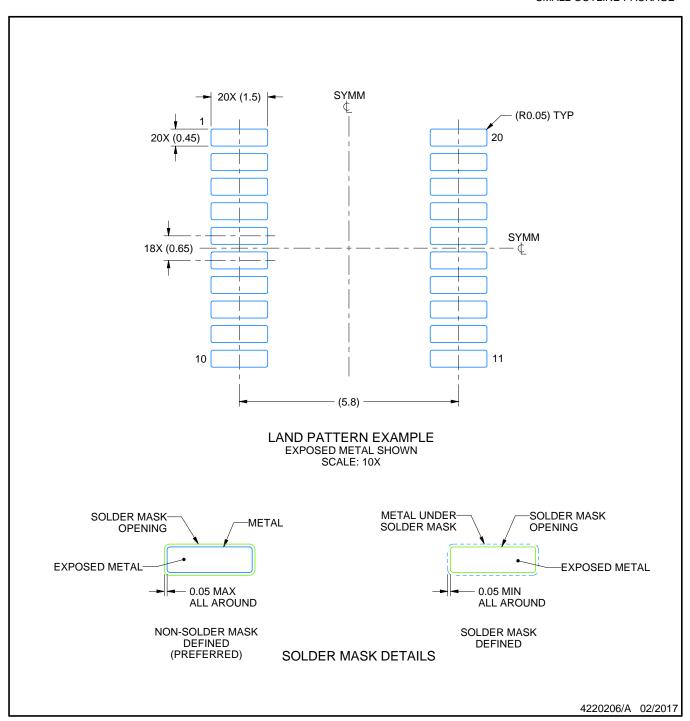
NOTES:

- 1. All linear dimensions are in millimeters. Any dimensions in parenthesis are for reference only. Dimensioning and tolerancing per ASME Y14.5M.

 2. This drawing is subject to change without notice.

 3. This dimension does not include mold flash, protrusions, or gate burrs. Mold flash, protrusions, or gate burrs shall not
- exceed 0.15 mm per side.
- 4. This dimension does not include interlead flash. Interlead flash shall not exceed 0.25 mm per side.
- 5. Reference JEDEC registration MO-153.



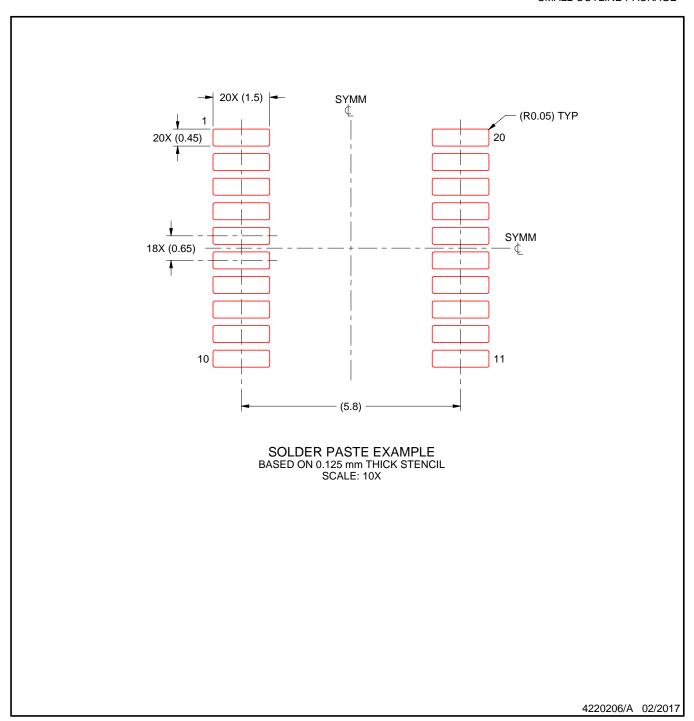


NOTES: (continued)

6. Publication IPC-7351 may have alternate designs.

7. Solder mask tolerances between and around signal pads can vary based on board fabrication site.



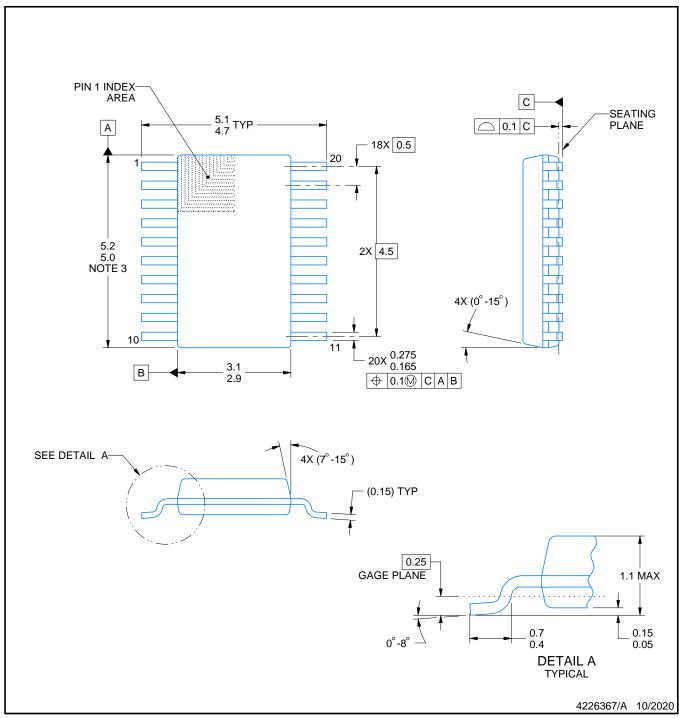


NOTES: (continued)

- 8. Laser cutting apertures with trapezoidal walls and rounded corners may offer better paste release. IPC-7525 may have alternate design recommendations.
- 9. Board assembly site may have different recommendations for stencil design.







NOTES:

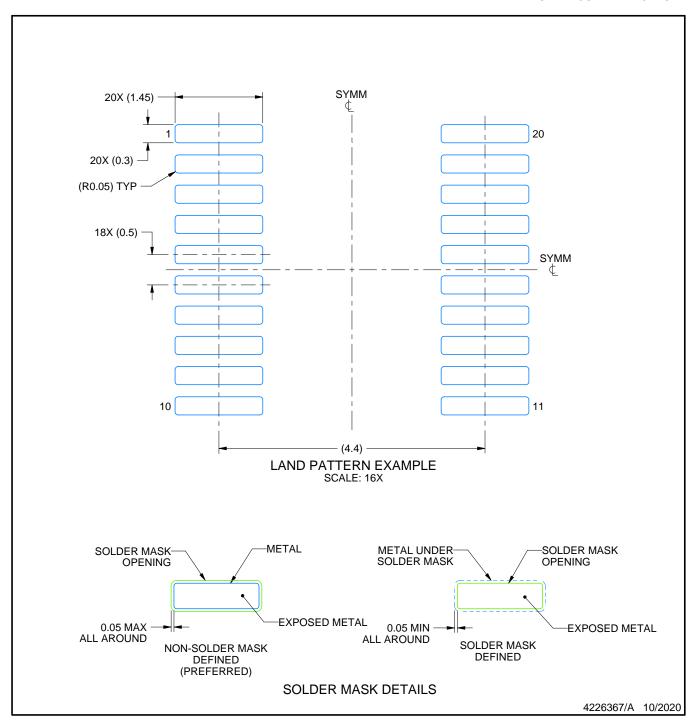
PowerPAD is a trademark of Texas Instruments.

- 1. All linear dimensions are in millimeters. Any dimensions in parenthesis are for reference only. Dimensioning and tolerancing per ASME Y14.5M.

 2. This drawing is subject to change without notice.

 3. This dimension does not include mold flash, protrusions, or gate burrs. Mold flash, protrusions, or gate burrs shall not
- exceed 0.15 mm per side.
- 4. No JEDEC registration as of September 2020.
- 5. Features may differ or may not be present.

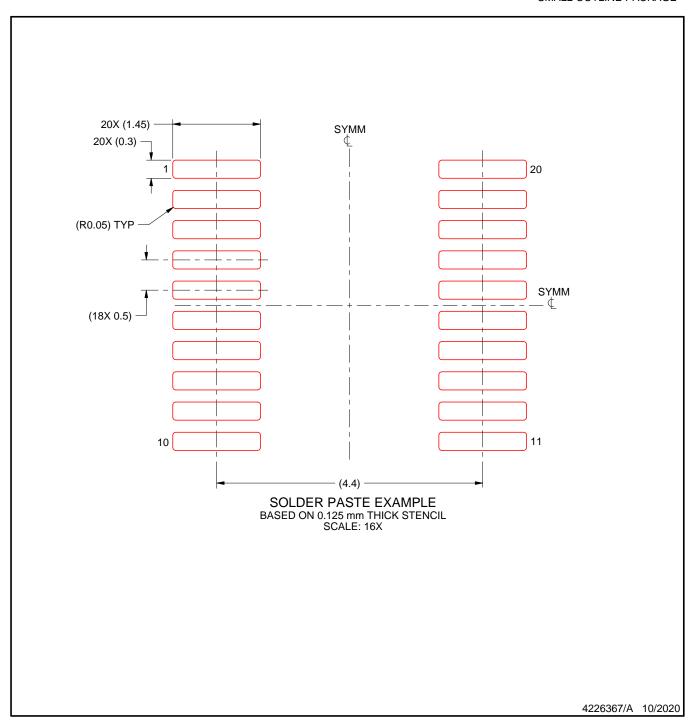




NOTES: (continued)

- 6. Publication IPC-7351 may have alternate designs.
- 7. Solder mask tolerances between and around signal pads can vary based on board fabrication site.
- 8. This package is designed to be soldered to a thermal pad on the board. For more information, see Texas Instruments literature numbers SLMA002 (www.ti.com/lit/slma002) and SLMA004 (www.ti.com/lit/slma004).
- 9. Size of metal pad may vary due to creepage requirement.
- 10. Vias are optional depending on application, refer to device data sheet. It is recommended that vias under paste be filled, plugged or tented.





NOTES: (continued)

- 11. Laser cutting apertures with trapezoidal walls and rounded corners may offer better paste release. IPC-7525 may have alternate design recommendations.
- 12. Board assembly site may have different recommendations for stencil design.



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